

SOT-23 Plastic-Encapsulate Transistors

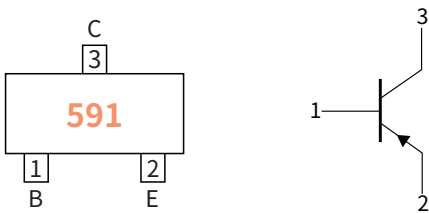
Features

- Power dissipation of 250mW
- PNP Low equivalent on-resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260°C

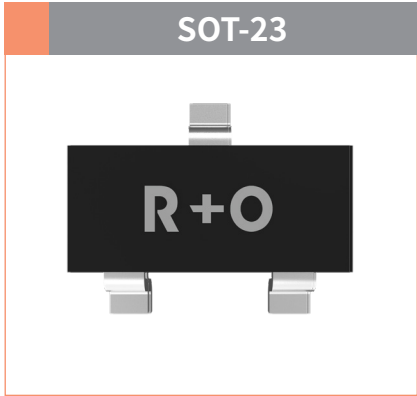
Mechanical Data

- Case: SOT-23
Molding compound meets UL 94V-0 flammability rating, RoHS-compliant,halogen-free
- Terminals: Solder plated, solderable per MIL-STD-750,Method 2026

Function Diagram



Collector-Base Voltage
VCBO -80V
Collector Current
-1.0 Ampere



Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Collector-Base Voltage	V_{CBO}	V	-80
Collector-Emitter Voltage	V_{CEO}		-60
Emitter-Base Voltage	V_{EBO}		-5.0
Collector Current	I_C	A	-1.0
Peak Pulse Collector Current	I_{CM}	A	-2.0
Collector Power Dissipation	P_C	mW	250
Storage temperature	T_{stg}	°C	-55 ~+150
Junction temperature	T_j	°C	-55 ~+150
Typical Thermal Resistance	$R_{\theta JA}$	°C /W	500

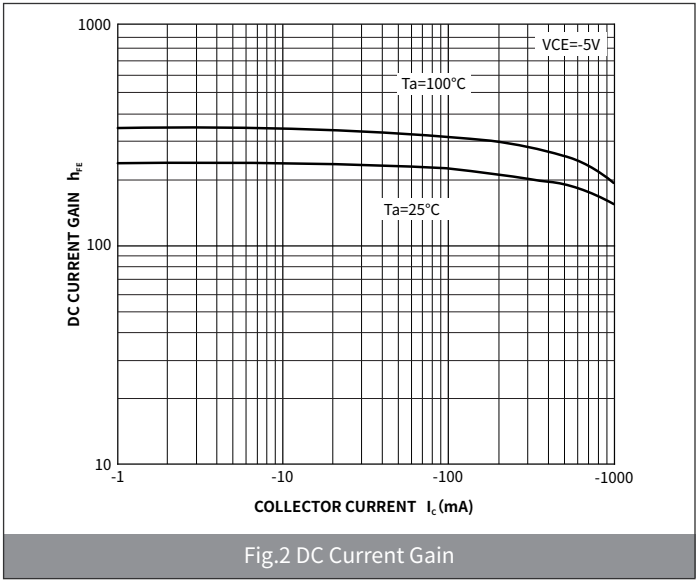
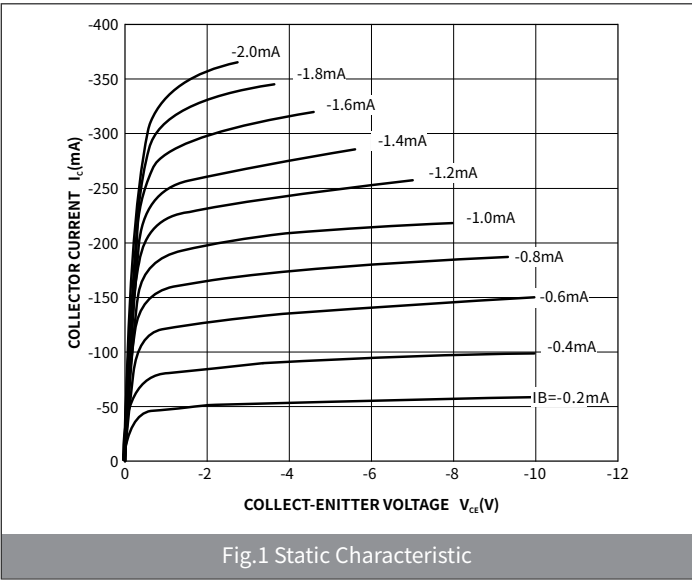
Small-signal Characteristics

ITEM	SYMBOL	Condition	UNIT	Min	Typ	Max
Transition frequency	f_T	$I_C = -50mA, V_{CE} = -10V$	MHz	150	—	—

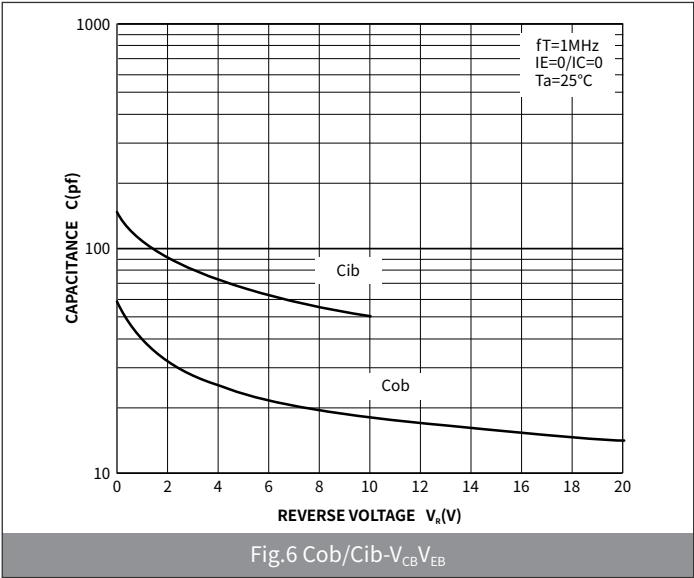
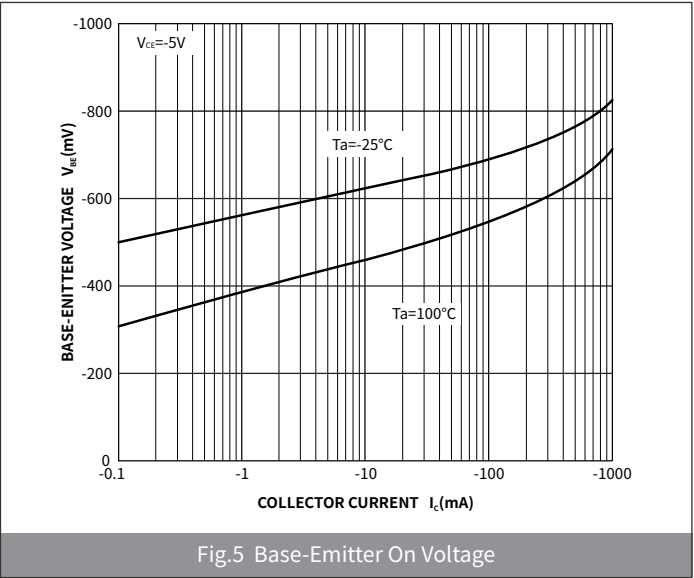
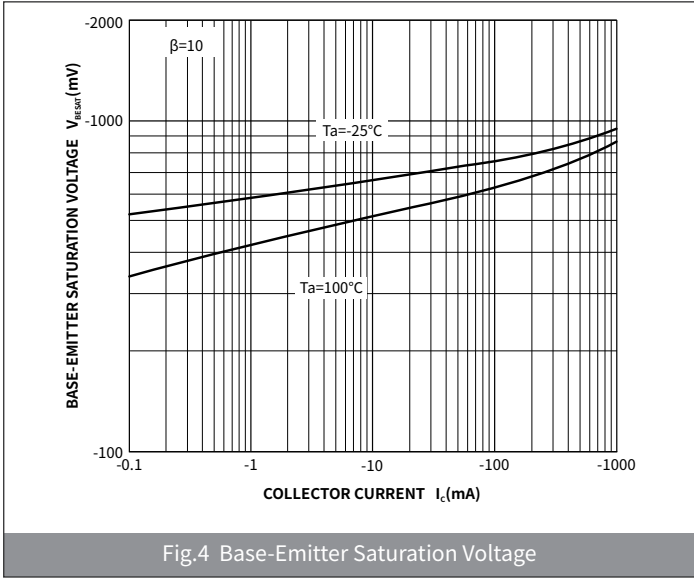
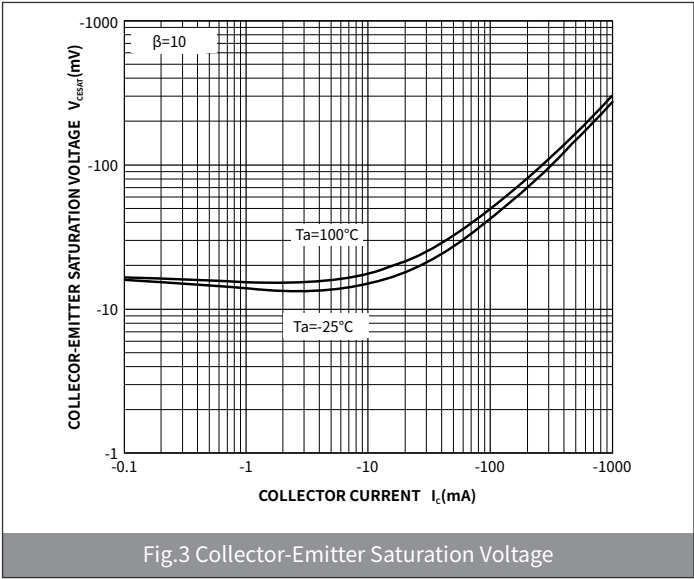
● Electrical Characteristics (Ta=25°C Unless otherwise noted)

PARAMETER	SYMBOL	UNIT	Condition	Min	Typ	Max
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	V	$I_C=-100\mu A, I_E=0$	-80	—	—
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$		$I_C=-10mA, I_B=0$	-60	—	—
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$		$I_E=-100\mu A, I_C=0$	-5.0	—	—
Collector-Base cut-off current	I_{CBO}	nA	$V_{CB}=-60V, I_E=0$	—	—	-100
Emitter-Base cut-off current	I_{EBO}		$V_{EB}=-4.0V, I_C=0$	—	—	-100
DC Current Gain	$h_{FE(1)}$	—	$I_C=-1mA, V_{CE}=-5.0V$	100	—	300
	$h_{FE(2)}$	—	$I_C=-500mA, V_{CE}=-5.0V$	100	—	300
	$h_{FE(3)}$	—	$I_C=-1.0A, V_{CE}=-5.0V$	80	—	300
	$h_{FE(4)}$	—	$I_C=-2.0A, V_{CE}=-5.0V$	15	—	300
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	V	$I_C=-500mA, I_B=-50mA$	—	—	-0.3
		V	$I_C=-1000mA, I_B=-100mA$			-0.6
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	V	$I_C=-1000mA, I_B=-100mA$	—	—	-1.2
Base-Emitter On Voltage	$V_{BE(on)}$	V	$V_{CE}=-5V, I_C=-1000mA$	—	—	-1
Output Capacitance	C_{ob}	pF	$V_{CB}=-10V, I_E=0, f=1MHZ$	—	10	—

● Ratings And Characteristics Curves (Ta=25°C Unless otherwise specified)



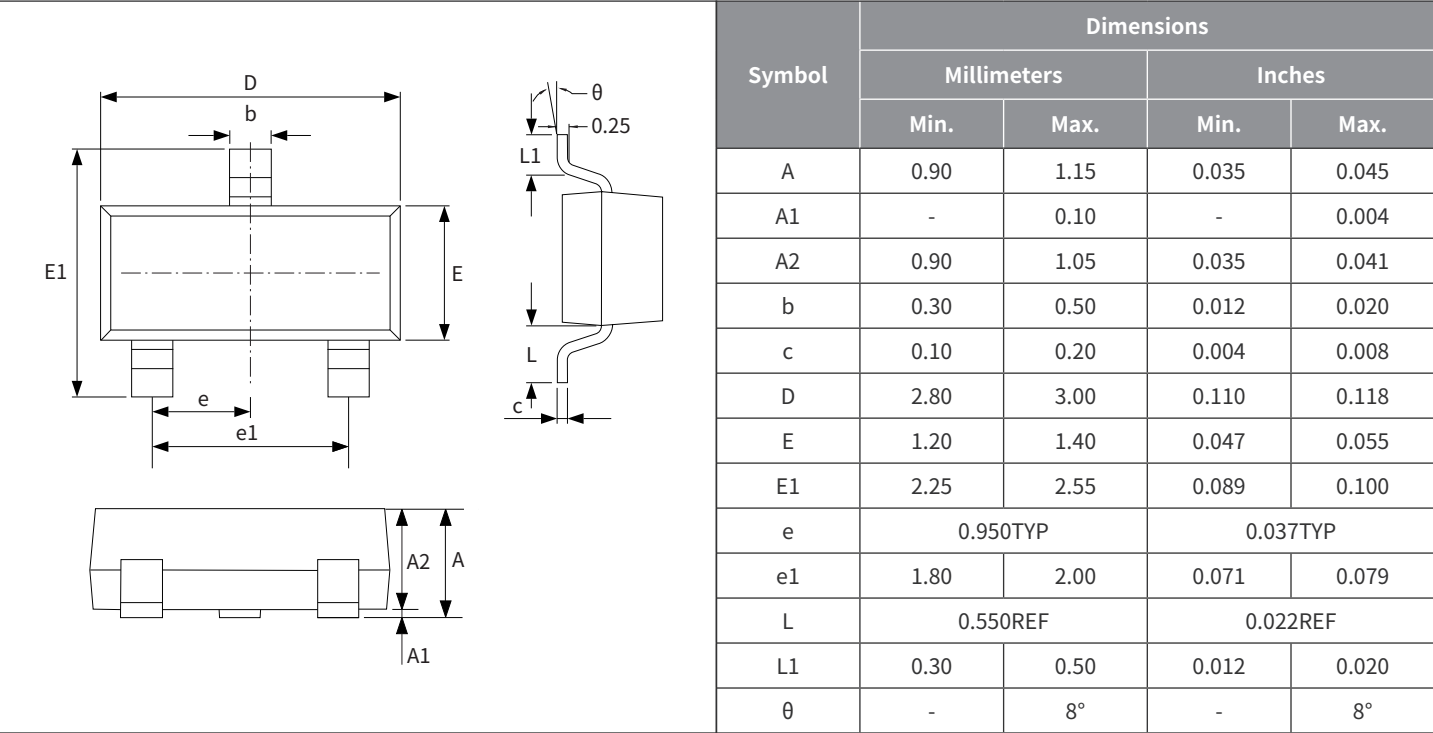
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Ordering Information

Table with 7 columns: PACKAGE, PACKAGE CODE, UNIT WEIGHT(g), REEL(pcs), BOX(pcs), CARTON(pcs), DELIVERY MODE. Row 1: SOT-23, R1, 0.008, 3000, 45000, 180000, 7"

Package Outline Dimensions (SOT-23)



Suggested Pad Layout

